

# High Voltage Switching Diode

## BAS19L, BAS20L, BAS21L, BAS21DW5

### Features

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant
- S and NSV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

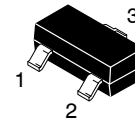
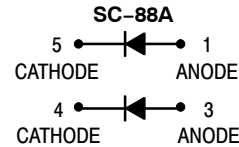
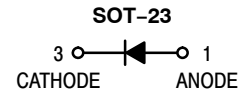
### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	$V_R$	120 200 250	Vdc
Repetitive Peak Reverse Voltage	$V_{RRM}$	120 200 250	Vdc
Continuous Forward Current	$I_F$	200	mAdc
Peak Forward Surge Current (1/2 Cycle, Sine Wave, 60 Hz)	$I_{FSM}$	2	A
Repetitive Peak Forward Current (Pulse Train: $T_{ON} = 1$ s, $T_{OFF} = 0.5$ s)	$I_{FRM}$	0.6	A
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	°C
Power Dissipation (Note 1)	$P_D$	385	mW
Electrostatic Discharge	ESD	HM < 500 MM < 400	V V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Mounted on FR-5 Board = 1.0 x 0.75 x 0.062 in.

## HIGH VOLTAGE SWITCHING DIODE

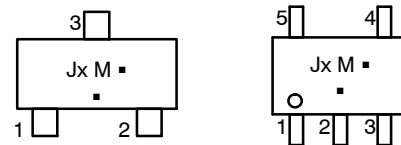


SOT-23 (TO-236)  
CASE 318  
STYLE 8



SC-88A (SOT-353)  
CASE 419A

### MARKING DIAGRAMS



- x = P, R, or S
- P = BAS19L
- R = BAS20L
- S = BAS21L or BAS21DW5
- M = Date Code
- = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon the manufacturing location.

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

# BAS19L, BAS20L, BAS21L, BAS21DW5

## Thermal Characteristics (SOT-23)

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 2) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	225	mW
		1.8	mW/ $^\circ\text{C}$
Thermal Resistance Junction-to-Ambient (SOT-23)	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate (Note 3) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300	mW
		2.4	mW/ $^\circ\text{C}$
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

## Thermal Characteristics (SC-88A)

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 4)	$P_D$	385	mW
Thermal Resistance - Junction-to-Ambient Derate Above $25^\circ\text{C}$	$R_{\theta JA}$	328	$^\circ\text{C}/\text{W}$
		3.0	mW/ $^\circ\text{C}$
Maximum Junction Temperature	$T_{Jmax}$	150	$^\circ\text{C}$
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

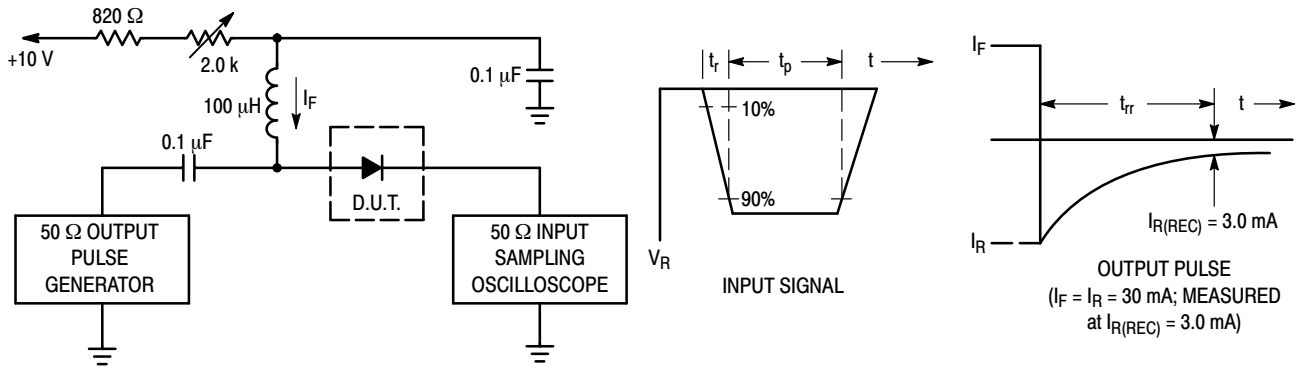
2. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
3. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.
4. Mounted on FR-5 Board =  $1.0 \times 0.75 \times 0.062$  in.

## Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
Reverse Voltage Leakage Current ( $V_R = 100$ Vdc) ( $V_R = 150$ Vdc) ( $V_R = 200$ Vdc) ( $V_R = 100$ Vdc, $T_J = 150^\circ\text{C}$ ) ( $V_R = 150$ Vdc, $T_J = 150^\circ\text{C}$ ) ( $V_R = 200$ Vdc, $T_J = 150^\circ\text{C}$ )	$I_R$	-	BAS19	0.1	$\mu\text{A}_{dc}$
			BAS20	0.1	
			BAS21	0.1	
			BAS19	100	
			BAS20	100	
			BAS21	100	
Reverse Breakdown Voltage ( $I_{BR} = 100$ $\mu\text{A}_{dc}$ ) ( $I_{BR} = 100$ $\mu\text{A}_{dc}$ ) ( $I_{BR} = 100$ $\mu\text{A}_{dc}$ )	$V_{(BR)}$	-	BAS19	120	Vdc
			BAS20	200	
			BAS21	250	
Forward Voltage ( $I_F = 100$ mA $_{dc}$ ) ( $I_F = 200$ mA $_{dc}$ )	$V_F$	-	-	1.0	Vdc
			-	1.25	
Diode Capacitance ( $V_R = 0$ , $f = 1.0$ MHz)	$C_D$	-	5.0	pF	
Reverse Recovery Time ( $I_F = I_R = 30$ mA $_{dc}$ , $I_{R(REC)} = 3.0$ mA $_{dc}$ , $R_L = 100$ )	$t_{rr}$	-	50	ns	

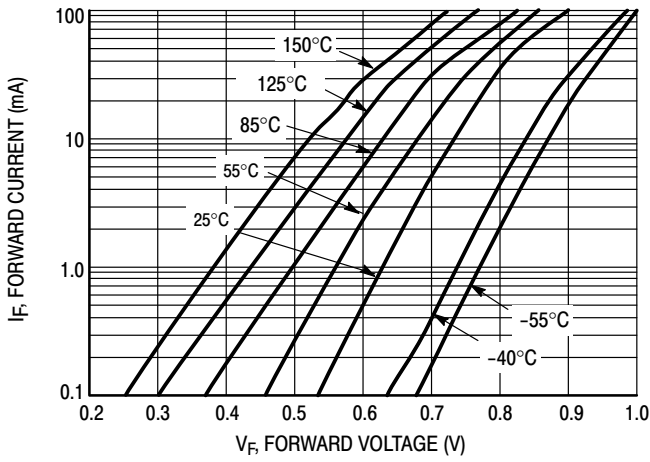
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# BAS19L, BAS20L, BAS21L, BAS21DW5

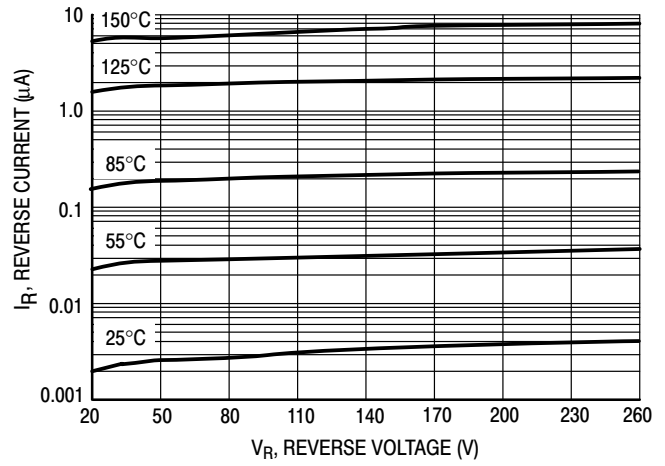


- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 30 mA.  
 2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 30 mA.  
 3.  $t_p \gg t_{rr}$

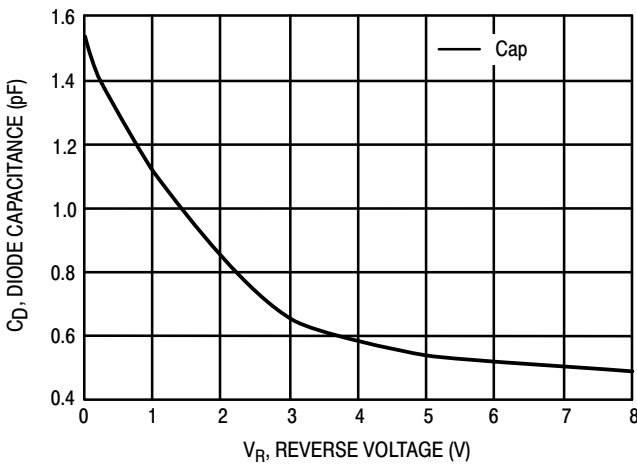
**Figure 1. Recovery Time Equivalent Test Circuit**



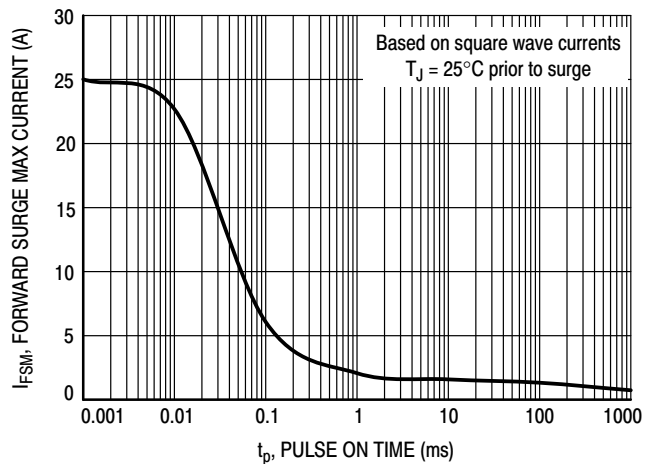
**Figure 2.  $V_F$  vs.  $I_F$**



**Figure 3.  $I_R$  vs.  $V_R$**



**Figure 4. Capacitance**



**Figure 5. Forward Surge Current**

## BAS19L, BAS20L, BAS21L, BAS21DW5

### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
BAS19LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
BAS19LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
NSVBAS19LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel
BAS20LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
BAS20LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
NSVBAS20LT3G*	SOT-23 (Pb-Free)	10000 / Tape & Reel
SBAS20LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel
BAS21LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
SBAS21LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel
BAS21LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
SBAS21LT3G*	SOT-23 (Pb-Free)	10000 / Tape & Reel
BAS21DW5T1G	SC-88A (Pb-Free)	3000 / Tape & Reel
SBAS21DW5T1G*	SC-88A (Pb-Free)	3000 / Tape & Reel
SBAS21DW5T3G*	SC-88A (Pb-Free)	10000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*S and NSV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

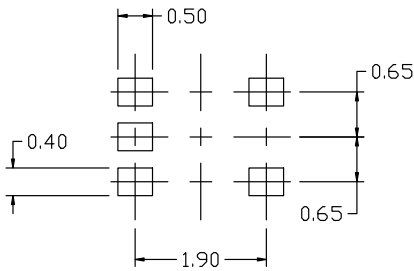
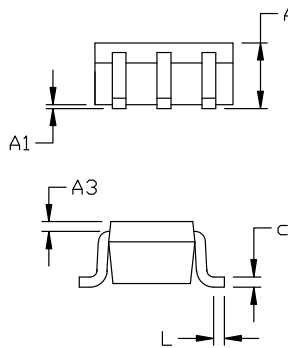
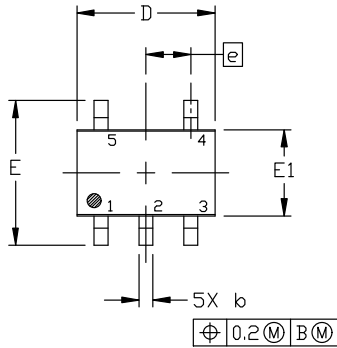
# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



SCALE 2:1

## SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

DATE 11 APR 2023



### RECOMMENDED MOUNTING FOOTPRINT

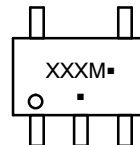
\* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. 419A-01 OBSOLETE. NEW STANDARD 419A-02
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.80	0.95	1.10
A1	---	---	0.10
A3	0.20 REF		
b	0.10	0.20	0.30
c	0.10	---	0.25
D	1.80	2.00	2.20
E	2.00	2.10	2.20
E1	1.15	1.25	1.35
e	0.65 BSC		
L	0.10	0.15	0.30

### GENERIC MARKING DIAGRAM\*



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

M = Date Code

▪ = Pb-Free Package

(Note: Microdot may be in either location)

#### STYLE 1:

1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

#### STYLE 2:

1. ANODE
2. EMITTER
3. BASE
4. COLLECTOR
5. CATHODE

#### STYLE 3:

1. ANODE 1
2. N/C
3. ANODE 2
4. CATHODE 2
5. CATHODE 1

#### STYLE 4:

1. SOURCE 1
2. DRAIN 1/2
3. SOURCE 1
4. GATE 1
5. GATE 2

#### STYLE 5:

1. CATHODE
2. COMMON ANODE
3. CATHODE 2
4. CATHODE 3
5. CATHODE 4

#### STYLE 6:

1. EMITTER 2
2. BASE 2
3. EMITTER 1
4. COLLECTOR
5. COLLECTOR 2/BASE 1

#### STYLE 7:

1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

#### STYLE 8:

1. CATHODE
2. COLLECTOR
3. N/C
4. BASE
5. EMITTER

#### STYLE 9:

1. ANODE
2. CATHODE
3. ANODE
4. ANODE
5. ANODE

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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